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CONTENTS

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BRIEF REPORTS

Electronic structure: wide-band, narrow-band, and strongly correlated systems

- Local environment of tin in layered $\text{SnSe}_{2x}\text{S}_{2(1-x)}$ compounds by ^{119}Sn Mössbauer spectroscopy 6371
C. Pérez Vicente, J. L. Tirado, P. E. Lippens, and J. C. Jumas
- Solution of a supersymmetric model of correlated electrons 6376
M. J. Martins and P. B. Ramos
- Electronic structure of SrRuO_3 6380
K. Fujioka, J. Okamoto, T. Mizokawa, A. Fujimori, I. Hase, M. Abbate, H. J. Lin, C. T. Chen, Y. Takeda, and M. Takano
- Raman vs Rayleigh scattering in the soft-x-ray region 6384
Eiichi Hanamura, Hidekatsu Suzuura, Akane Agui, and Shik Shin
- Zero-temperature limits of nonlinear conduction of the quasi-one-dimensional conductor TaS_3 with charge-density waves 6388
S. V. Zaitsev-Zotov, G. Remenyi, and P. Monceau

Semiconductors I: bulk

- EPR identification of the $\langle 100 \rangle$ -split $[\text{B-N}]^+$ interstitialcy in diamond 6392
J. Isoya, H. Kanda, and Y. Morita
- Anomalous diffusion of tin in silicon 6396
Per Kringhøj and Arne Nylandsted Larsen
- Anisotropy in the electron inelastic scattering potential for plasmon excitation in silicon 6400
A. J. Forsyth, A. E. Smith, and T. W. Josefsson
- Local vibrational modes in GaAs under hydrostatic pressure 6404
M. D. McCluskey, E. E. Haller, J. Walker, N. M. Johnson, J. Vetterhöffer, J. Weber, T. B. Joyce, and R. C. Newman
- Hole response time and the experimental test of the Einstein relation 6408
R. Brüggemann
- Magnetic-field effects on the hysteresis in semiconductors with an S-shaped negative differential conductivity 6412
Fu-Sin Lee and Yi-Chen Cheng

Semiconductors II: surfaces, interfaces, microstructures, and related topics

- Envelope of Weiss oscillations and the role of disorder in surface superlattices 6416
Y. Paltiel, U. Meirav, D. Mahalu, and Hadas Shtrikman
- Intra-atomic correlation effects and the electronic and magnetic properties in nanotubes 6420
R. J. Tarento, P. Joyes, M. T. Le Houcq, and J. Van de Walle
- Effect of long-range Coulomb interaction on shot-noise suppression in ballistic transport 6424
T. González, O. M. Bulashenko, J. Mateos, D. Pardo, and L. Reggiani
- Electronic structures in circular, elliptic, and triangular quantum dots 6428
T. Ezaki, N. Mori, and C. Hamaguchi
- Anomalously large negative differential resistance due to Γ -X resonances in type-I GaAs/AlAs superlattices 6432
M. Hosoda, N. Ohtani, K. Tominaga, H. Mimura, and T. Watanabe

(Continued)

Magnetoresistance of a weakly disordered III-V semiconductor quantum well in a magnetic field parallel to interfaces	6436
A. G. Mal'shukov, K. A. Chao, and M. Willander	
Density of states for ballistic electron in external fields	6440
M. Kubisa and W. Zawadzki	
EPR study of Mn^{2+} electronic states for the nanosized ZnS:Mn powder modified by acrylic acid	6444
T. Igarashi, T. Isobe, and M. Senna	

Surface physics, low-dimensional systems, and related topics

Inelastic energy loss in low-energy ion-surface collisions	6446
Peter Kürpick	
Effect of viscosity on the fission of metallic clusters	6450
P. Fröbrich	
Speckle in coherent x-ray reflectivity from Si(111) wafers	6454
J. L. Libbert, R. Pindak, S. B. Dierker, and I. K. Robinson	
Epitaxy controlled by self-assembled nanometer-scale structures	6458
T. M. Parker, L. K. Wilson, N. G. Condon, and F. M. Leibsle	
Search for evidence of commensurate argon-on-graphite films near monolayer completion	6462
D. E. Johnson, J. M. Phillips, and J. Z. Larese	
Prediction of the structures of clusters of C_{60} molecules using an atom-atom interaction potential	6466
J. García-Rodeja, C. Rey, and L. J. Gallego	
STM study of one-dimensional cluster formation of fullerenes: Dimerization of Y@C_{82}	6470
Y. Hasegawa, Y. Ling, S. Yamazaki, T. Hashizume, H. Shinohara, A. Sakai, H. W. Pickering, and T. Sakurai	
Characterization of interfacial roughness in Co/Cu multilayers by x-ray scattering	6474
T. Gu, A. I. Goldman, and M. Mao	
Fluid interface fluctuations within the generalized Derjaguin approximation	6478
G. Palasantzas and G. Backx	
Surface phonons of $\text{H:Si(110)-(1}\times\text{1)}$	6482
Volker Gräschus, Albert Mazur, and Johannes Pollmann	
Model of adsorbate-induced missing-row reconstructions of the (110) surface of fcc metals	6486
P. J. Kundrotas, S. Lapinskas, and A. Rosengren	
Interference shift due to local variation of the attractive well in atom-surface scattering from small islands	6490
S. Terreni, P. Cantini, M. Canepa, and L. Mattera	
Effects of lattice fluctuations on electronic transmission in metal/conjugated-oligomer/metal structures	6494
Z. G. Yu, D. L. Smith, A. Saxena, and A. R. Bishop	
Temperature dependence of the direct band gap of Si-containing carbon nitride crystalline films	6498
D. Y. Lin, C. F. Li, Y. S. Huang, Y. C. Jong, Y. F. Chen, L. C. Chen, C. K. Chen, K. H. Chen, and D. M. Bhusari	
Intraband transitions in simple metals: Evidence for non-Drude-like near-IR optical properties	6502
H.-G. Boyen, R. Gampp, P. Oelhafen, B. Heinz, P. Ziemann, Ch. Lauinger, and St. Herminghaus	

ARTICLES**Electronic structure: wide-band, narrow-band, and strongly correlated systems**

Experimental studies of the mechanism of the electro-optical effect in blue bronze	6506
M. E. Itkis, B. M. Emerling, and J. W. Brill	

(Continued)

Theory of many-fermion systems	6513
D. Belitz and T. R. Kirkpatrick	
Estimation of properties of low-lying excited states of Hubbard models: A multiconfigurational symmetrized projector quantum Monte Carlo approach	6542
Bhargavi Srinivasan, S. Ramasesha, and H. R. Krishnamurthy	
Finite-temperature spectral functions of strongly correlated one-dimensional electron systems	6555
Karlo Penc and Mohammed Serhan	
Periodic Anderson model with correlated conduction electrons	6559
Tom Schork and Stefan Blawid	
<i>N</i> -chain Hubbard model in weak coupling	6569
Hsiu-Hau Lin, Leon Balents, and Matthew P. A. Fisher	
Efficient <i>ab initio</i> tight binding	6594
Andrew P. Horsfield	
Cumulant approach to the low-temperature thermodynamics of many-body systems	6603
Holger Köhler, Matthias Vojta, and Klaus W. Becker	
Photoemission study of the electronic structure of PtGa ₂	6615
Li-Shing Hsu and K.-L. Tsang	
Experimental band structure of semimetal bismuth	6620
G. Jezequel, J. Thomas, and I. Pollini	
Metal-insulator transition in AC ₆₀ : RbC ₆₀ and KC ₆₀	6627
K. Khazeni, Vincent H. Crespi, J. Hone, A. Zettl, and Marvin L. Cohen	
X-ray edge singularity in integrable lattice models of correlated electrons	6631
Fabian H. L. Eßler and Holger Frahm	
Semiconductors I: bulk	
Hydrogen molecules and hydrogen-related defects in crystalline silicon	6642
N. Fukata, S. Sasaki, K. Murakami, K. Ishioka, K. G. Nakamura, M. Kitajima, S. Fujimura, J. Kikuchi, and H. Haneda	
Core polarization in solids: Formulation and application to semiconductors	6648
Eric L. Shirley, Xuejun Zhu, and Steven G. Louie	
<i>Ab initio</i> study of silicon in the <i>R8</i> phase	6662
Bernd G. Pfrommer, Michel Côté, Steven G. Louie, and Marvin L. Cohen	
<i>p-d</i> exchange interaction for 3 <i>d</i> transition-metal impurities in II-VI semiconductors	6669
T. Mizokawa and A. Fujimori	
Bound magnetic polarons in <i>p</i> -type Cu ₂ Mn _{0.9} Zn _{0.1} SnS ₄	6673
G. H. McCabe, T. Fries, M. T. Liu, Y. Shapira, L. R. Ram-Mohan, R. Kershaw, A. Wold, C. Fau, M. Averous, and E. J. McNiff, Jr.	
Photobleaching and spectral diffusion in disordered media	6681
M. C. J. M. Vissenberg and M. J. M. de Jong	
Persistent photoconductivity at elevated temperatures in Cd _{1-x} Mn _x Te:In	6689
C. Leighton, I. Terry, and P. Becla	
Effective-medium method for hopping transport in a magnetic field	6698
O. Bleibaum, H. Böttger, and V. V. Bryksin	
NMR study of the diluted magnetic semiconductor alloys Cd _{1-x} Mn _x Se, Cd _{1-x} Co _x Se, and Cd _{1-x} Fe _x Se	6712
V. Ladizhansky, A. Faraggi, V. Lyahovitskaya, and S. Vega	

Semiconductors II: surfaces, interfaces, microstructures, and related topics

As on InP(110) studied within density-functional theory	6719
U. Grossner, W. G. Schmidt, and F. Bechstedt	
Electronic structure of Mn on the GaAs(001) surface	6727
Zongxian Yang, Kaiming Zhang, Sanhuang Ke, and Xide Xie	
Tunneling conductance and Coulomb-blockade peak splitting of two quantum dots connected by a quantum point contact	6732
Yu-Liang Liu	
Electronic energy levels in semiconductor nanocrystals: A Wannier function approach	6737
Ari Mizel and Marvin L. Cohen	
Far-infrared absorption of acoustic and optical magnetoplasmons in double-layered quantum wires	6742
Christoph Steinebach, Detlef Heitmann, and Vidar Gudmundsson	
Correlations, inhomogeneous screening, and suppression of spin splitting in quantum wires at strong magnetic fields	6748
O. G. Balev and P. Vasilopoulos	
Quantum magnetotransport properties of short quantum wires	6758
Tae-ik Park, Godfrey Gumbs, and M. Pepper	
Few-electron ground states of charge-tunable self-assembled quantum dots	6764
B. T. Miller, W. Hansen, S. Manus, R. J. Luyken, A. Lorke, J. P. Kotthaus, S. Huant, G. Medeiros-Ribeiro, and P. M. Petroff	
Optical anisotropy of InAs submonolayer quantum wells in a (311) GaAs matrix	6770
Y. H. Chen, Z. Yang, Z. G. Wang, B. Xu, J. B. Liang, and J. J. Qian	
Relativistic effects in electron-energy-loss-spectroscopy observations of the Si/SiO ₂ interface plasmon peak	6774
P. Moreau, N. Brun, C. A. Walsh, C. Colliex, and A. Howie	
Surface electrical conduction due to carrier doping into a surface-state band on Si(111)- $\sqrt{3}\times\sqrt{3}$ -Ag	6782
Yuji Nakajima, Sakura Takeda, Tadaaki Nagao, Shuji Hasegawa, and Xiao Tong	
Generalized Chern-Simons theory of composite fermions in bilayer Hall systems	6788
R. Rajaraman	
Critical comparison of classical field theory and microscopic wave functions for skyrmions in quantum Hall ferromagnets	6795
M. Abolfath, J. J. Palacios, H. A. Fertig, S. M. Girvin, and A. H. MacDonald	
Quantum Hall Skyrmions with higher topological charge	6805
D. Lilliehöök, K. Lejnell, A. Karlhede, and S. L. Sondhi	
Global symmetries of quantum Hall systems: Lattice description	6810
Leonid P. Pryadko	
Suppression of chaotic dynamics and localization of two-dimensional electrons by a weak magnetic field	6823
M. M. Fogler, A. Yu. Dobin, V. I. Perel, and B. I. Shklovskii	
Coherent states of alternating current	6839
D. A. Ivanov, H. W. Lee, and L. S. Levitov	
Optical properties of monoclinic SnI ₂ from relativistic first-principles theory	6851
P. Ravindran, A. Delin, R. Ahuja, B. Johansson, S. Auluck, J. M. Wills, and O. Eriksson	
Metastable excitons in ZnSe/Zn _{1-x} Fe _x Se quantum wells	6862
W. Y. Yu, S. Stoltz, A. Petrou, J. Warnock, and B. T. Jonker	
Relaxation of hot excitons in inhomogeneously broadened Cd _x Zn _{1-x} Se/ZnSe nanostructures	6868
G. Bacher, R. Spiegel, T. Kümmell, O. Breitwieser, A. Forchel, B. Jobst, D. Hommel, and G. Landwehr	
Miniband effects on hot-electron photoluminescence polarization in GaAs/AlAs superlattices	6871
V. F. Sapega, V. I. Perel', A. Yu. Dobin, D. N. Mirlin, I. A. Akimov, T. Ruf, M. Cardona, and K. Eberl	

(Continued)

Triple magnetopolarons in quantum wells	6880
I. G. Lang, V. I. Belitsky, A. Cantarero, L. I. Korovin, S. T. Pavlov, and M. Cardona	
Determination of nitrogen-acceptor spin-Hamiltonian parameters in ZnSe epilayers via spin-flip Raman spectroscopy	6889
Wolfram Heimbrodt, Catherine L. Orange, Daniel Wolverson, J. John Davies, Kozo Kimura, and Takafumi Yao	
Selective ion-channeling study of misfit dislocation grids in semiconductor heterostructures: Theory and experiments	6895
M. Mazzer, A. V. Drigo, F. Romanato, G. Salviati, and L. Lazzarini	
Stability and band offsets of polar GaN/SiC(001) and AlN/SiC(001) interfaces	6911
M. Städele, J. A. Majewski, and P. Vogl	
Auger scattering between Landau levels in a two-dimensional electron gas	6921
E. Tsitsishvili and Y. Levinson	
Quantum scattering, resonant states, and conductance fluctuations in an open square electron billiard	6931
I. V. Zozoulenko and K.-F. Berggren	
Yellow luminescence in <i>n</i> -type GaN epitaxial films	6942
H. M. Chen, Y. F. Chen, M. C. Lee, and M. S. Feng	
Surface physics, low-dimensional systems, and related topics	
Atomic-scale structure of a SrTiO ₃ bicrystal boundary studied by scanning tunneling microscopy	6947
Q. D. Jiang, X. Q. Pan, and J. Zegenhagen	
Magic numbers in supported metal clusters	6952
Saroj K. Nayak, P. Jena, V. S. Stepanyuk, W. Hergert, and K. Wildberger	
Photoluminescence and resonant Raman spectra of silicon films produced by size-selected cluster beam deposition	6958
M. Ehbrecht, B. Kohn, F. Huisken, M. A. Laguna, and V. Paillard	
Surface self-diffusivity of TiO ₂ under high-pressure gas	6965
Makoto Nanko and Kozo Ishizaki	
Epitaxial rotation of two-dimensional rare-gas lattices on Ag(111)	6970
G. S. Leatherman, R. D. Diehl, M. Karimi, and G. Vidali	
Absolute luminescence efficiency of ion-bombarded solid argon	6975
D. E. Grosjean, R. A. Vidal, R. A. Baragiola, and W. L. Brown	
Thermal shift in the binding energy of bulk W 4 <i>f</i> _{7/2}	6982
H.-S. Tao, T. E. Madey, J. E. Rowe, and G. K. Wertheim	
Quantitative analysis of the frictional properties of solid materials at low loads. I. Carbon compounds	6987
Udo D. Schwarz, Oliver Zwörner, Peter Köster, and Roland Wiesendanger	
Quantitative analysis of the frictional properties of solid materials at low loads. II. Mica and germanium sulfide ..	6997
Udo D. Schwarz, Oliver Zwörner, Peter Köster, and Roland Wiesendanger	
Interaction mechanism of N ₂ with the Cr (110) surface	7001
T. C. Guimaraes, A. C. Pavão, C. A. Taft, and W. A. Lester, Jr.	
Energy loss and straggling for 50- and 100-keV H ⁺ ions passing through the Si(001)2×1-Sb surface	7011
Koji Sumitomo, Takashi Nishioka, Atsushi Ikeda, and Yoshiaki Kido	
Errata	
Erratum: Pair-distribution function and its coupling-constant average for the spin-polarized electron gas [Phys. Rev. B 46 , 12 947 (1992)]	7018
John P. Perdew and Yue Wang	

Erratum: Elastic constants and related properties of tetrahedrally bonded BN, AlN, GaN, and InN [Phys. Rev. B 53, 16310 (1996)]	7018
Kwiseon Kim, Walter R. L. Lambrecht, and Benjamin Segall	
Erratum: Tests of current models of intermolecular potentials against x-ray diffuse scattering in C ₆₀ [Phys. Rev. B 55, 2651 (1997)]	7019
Pascale Launois, Sylvain Ravy, and Roger Moret	
Erratum: Charge buildup by irradiation in metal-oxide–semiconductor structures at cryogenic temperatures: Basic mechanisms and influence of dose and dose rate [Phys. Rev. B 55, 7641 (1997)]	7022
Nicolas T. Fourches	
Erratum: Gradient-corrected correlation with nearly exact Kohn-Sham exchange: Calculations for Si and Ge [Phys. Rev. B 55, 9432 (1997)]	7022
D. M. Bylander and Leonard Kleinman	
Erratum: Specific heat of the two-dimensional Hubbard model [Phys. Rev. B 55, 12 918 (1997)]	7022
Daniel Duffy and Adriana Moreo	
Cumulative Author Index	7023